Hex Buffers / Drivers with Open Drain Outputs

# **HITACHI**

ADE-205-297A (Z) 2nd Edition February 2000

#### **Description**

The HD74LV07A has six buffers / drivers with open drain outputs in a 14-pin package. Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

#### **Features**

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V to 5.5 V)
- All outputs  $V_0$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V)
- Typical  $V_{OL}$  ground bounce < 0.8 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Typical  $V_{OH}$  undershoot > 2.3 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Output current  $\pm 8$  mA (@V<sub>CC</sub> = 3.0 V to 3.6 V),  $\pm 16$  mA (@V<sub>CC</sub> = 4.5 V to 5.5 V)

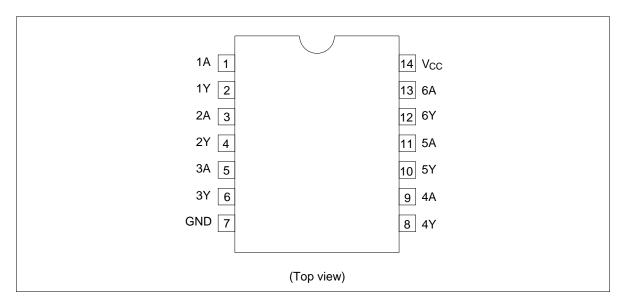
#### **Function Table**

Input A	Output Y
L	L
Н	Н

Note: H: High level L: Low level



## **Pin Arrangement**



#### **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V <sub>cc</sub>	-0.5 to 7.0	V	
Input voltage range*1	Vı	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	$-0.5$ to $V_{cc}$ + 0.5	V	Output: H or L
		-0.5 to 7.0	-	V <sub>cc</sub> : OFF
Input clamp current	I <sub>IK</sub>	-20	mA	V <sub>1</sub> < 0
Output clamp current	I <sub>OK</sub>	<b>-</b> 50	mA	V <sub>o</sub> < 0
Continuous output current	Io	35	mA	$V_{o} = 0$ to $V_{cc}$
Continuous current through $V_{cc}$ or GND	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air)*3	P <sub>T</sub>	785	mW	SOP
		500	-	TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

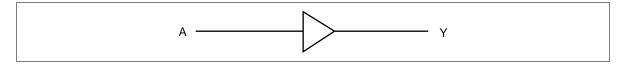
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

# **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V <sub>cc</sub>	2.0	5.5	V	
Input voltage range	V <sub>I</sub>	0	5.5	V	
Output voltage range	Vo	0	5.5	V	
Output current	I <sub>OL</sub>	_	50	μΑ	V <sub>cc</sub> = 2.0 V
		_	2	mA	$V_{cc}$ = 2.3 to 2.7 V
		_	8		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		_	16		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Input transition rise or fall rate	Δt/Δν	0	200	ns/V	$V_{cc} = 2.3 \text{ to } 2.7 \text{ V}$
		0	100		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

# Logic Diagram



#### **DC Electrical Characteristics**

#### • $Ta = -40 \text{ to } 85^{\circ}C$

Item	Symbol	V <sub>cc</sub> (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	2.0	1.5		_	V	
		2.3 to 2.7	$V_{cc} \times 0.7$	_	_	='	
		3.0 to 3.6	$V_{cc} \times 0.7$	_	_	-	
		4.5 to 5.5	$V_{cc} \times 0.7$	_	_	=	
	V <sub>IL</sub>	2.0	_	_	0.5	='	
		2.3 to 2.7	_	_	$V_{\text{CC}} \times 0.3$	-	
		3.0 to 3.6	_	_	$V_{\text{CC}} \times 0.3$	-	
		4.5 to 5.5	_	_	$V_{cc} \times 0.3$	-	
Output voltage	V <sub>OL</sub>	Min to Max	_	_	0.1	V	I <sub>OL</sub> = 50 μA
		2.3	_	_	0.4	='	I <sub>OL</sub> = 2 mA
		3.0	_	_	0.44	-	I <sub>OL</sub> = 8 mA
		4.5	_	_	0.55	-	I <sub>OL</sub> = 16 mA
Input current	I <sub>IN</sub>	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply current	I <sub>cc</sub>	5.5	_	_	20	μΑ	$V_{IN} = V_{CC}$ or GND, $I_{O} = 0$
Output leakage current	I <sub>OFF</sub>	0	_	_	5	μΑ	V <sub>o</sub> = 5.5 V
Input capacitance	C <sub>IN</sub>	3.3	_	2.3		pF	$V_1 = V_{CC}$ or GND

Note: For conditions shown as Min or Max use the appropriate values under recommended operating conditions.

# **Switching Characteristics**

## • $V_{CC} = 2.5 \pm 0.2 \text{ V}$

		Ta = 2	25°C		Ta = -4	40 to 85°C				
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propagation	t <sub>PLH</sub>	_	4.7	10.4	1.0	13.0	ns	C <sub>L</sub> = 15 pF	Α	Υ
delay time		_	9.5	15.2	1.0	18.0	=	C <sub>L</sub> = 50 pF	-	
	t <sub>PHL</sub>	_	5.4	10.4	1.0	13.0	_	C <sub>L</sub> = 15 pF	_	
		_	7.9	15.2	1.0	18.0	=	C <sub>L</sub> = 50 pF	-	

# • $V_{CC} = 3.3 \pm 0.3 \text{ V}$

		Ta = 2	25°C		Ta = -4	40 to 85°C				
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propagation	t <sub>PLH</sub>	_	4.0	7.1	1.0	8.5	ns	C <sub>L</sub> = 15 pF	А	Υ
delay time		_	7.3	10.6	1.0	12.0	_	C <sub>L</sub> = 50 pF	-	
	t <sub>PHL</sub>	_	4.3	7.1	1.0	8.5	=	C <sub>L</sub> = 15 pF	-	
		_	5.8	10.6	1.0	12.0	_	C <sub>L</sub> = 50 pF	-	

## • $V_{CC} = 5.0 \pm 0.5 V$

		Ta = 2	25°C		Ta = -4	10 to 85°C				
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propagation	t <sub>PLH</sub>	_	3.3	5.5	1.0	6.5	ns	C <sub>L</sub> = 15 pF	Α	Υ
delay time		_	5.6	7.5	1.0	8.5	_	C <sub>L</sub> = 50 pF	-	
	t <sub>PHL</sub>	_	3.4	5.5	1.0	6.5	_	C <sub>L</sub> = 15 pF	_	
		_	4.1	7.5	1.0	8.5		C <sub>L</sub> = 50 pF	-	

# **Operating Characteristics**

•  $C_L = 50 pF$ 

Ta	=	25°	C

Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Unit	<b>Test Conditions</b>
Power dissipation capacitance	$C_{\mathtt{PD}}$	3.3	_	9.6	_	pF	f = 10 MHz
		5.0	_	11.4	_		

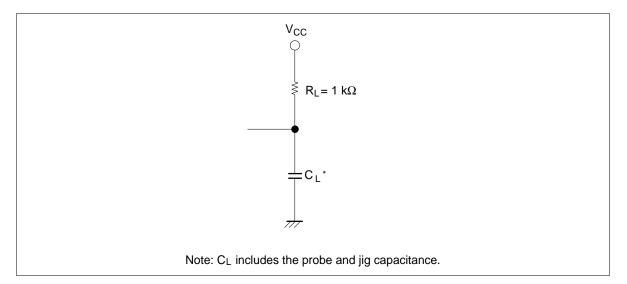
#### **Noise Characteristics**

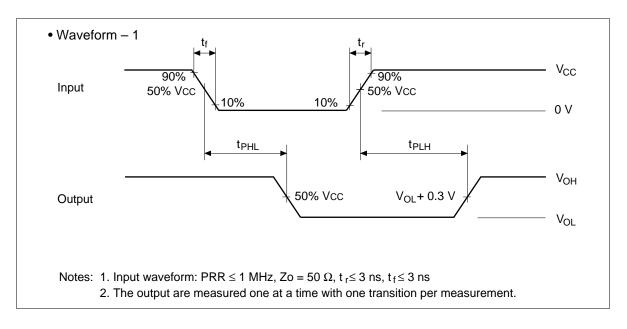
•  $C_L = 50 \text{ pF}$ 

1a = 23	5°C
---------	-----

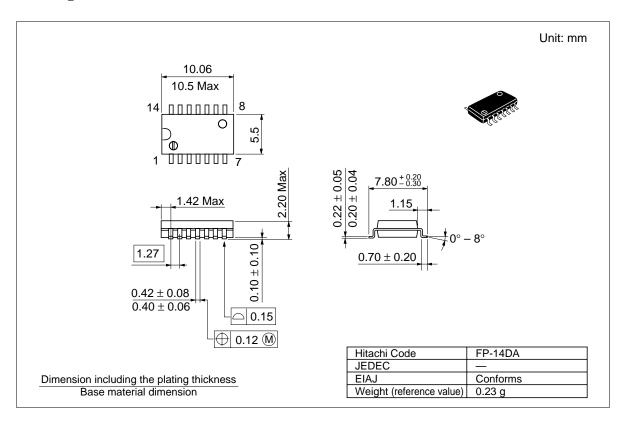
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Unit	<b>Test Conditions</b>
Quiet output, maximum dynamic V <sub>OL</sub>	$V_{OL(P)}$	3.3	_	0.3	0.8	V	
Quiet output, minimum dynamic V <sub>OL</sub>	$V_{OL(V)}$	3.3	_	-0.1	-0.8		
High-level dynamic input voltage	$V_{\text{IH }(D)}$	3.3	2.31	_	_	V	
Low-level dynamic input voltage	$V_{IL(D)}$	3.3	_	_	0.99		

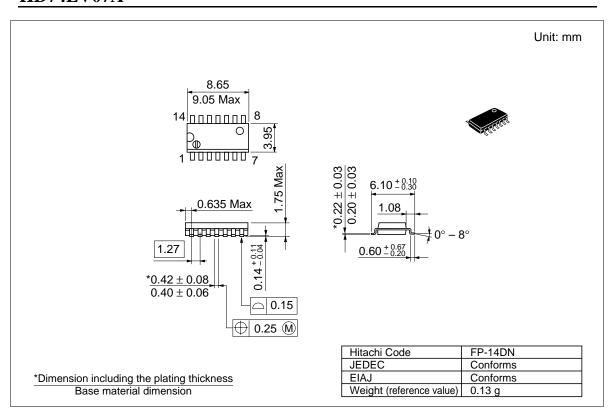
#### **Test Circuit**

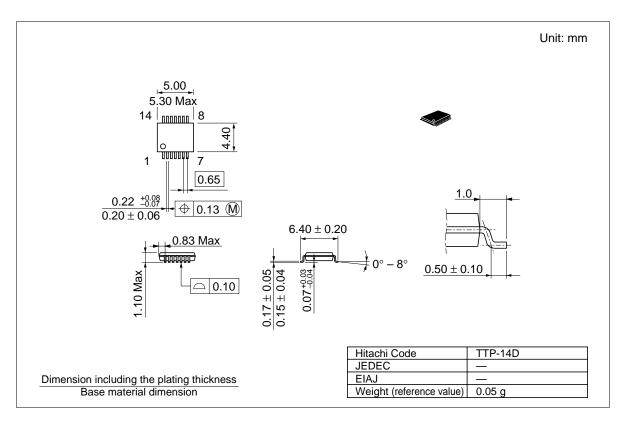




## **Package Dimensions**







#### **Cautions**

- 1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as in aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safe devices, so that the equipment incorporating the Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

# **HITACHI**

#### Hitachi, Ltd.

Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109 URL NorthAmerica : http:semio

NorthAmerica : http://www.hitachi.com/ Europe : http://www.hitachi-eu.com/hel/ecg Asia (Singapore) : http://www.has.hitachi.com.sg/grp3/sicd/index.htm Asia (HongKong) : http://www.hitachi.com.tw/E/Product/SICD\_Frame.htm

Japan : http://www.hitachi.co.jp/Sicd/index.htm

#### For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223

Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road

Electronic components Group

Hitachi Europe GmbH

Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower, World Finance Centre,
Harbour City, Canton Road, Tsim Sha Tsui,
Kowloon, Hong Kong
Tel: <852> (2) 735 9218
Fax: <852> (2) 730 0281

Telex: 40815 HITEC HX

Copyright ' Hitachi, Ltd., 2000. All rights reserved. Printed in Japan.

#### HITACHI